Reg No.:	Name:

APJ ABDUL KALAM TECHNOLOGICAL UNIVERSITY

Eighth Semester B.Tech Degree Supplementary Examination August 2021

Course Code: EC402 Course Name: NANOELECTRONICS

Max. Marks: 100 **Duration: 3 Hours** PART A Marks Answer any two full questions, each carries 15 marks. a) Explain ion implantation method of nanomaterial deposition. (10)b) DC sputtering cannot be used for fabricating non conducting layers. Justify the (5) statement. Explain laser ablation technique used for the fabrication of nanolayers. a) (5) b) Explain the features of triangular and parabolic quantum wells. (10)a) Explain any two characteristic lengths associated with mesoscopic systems. (5) Derive the expression for density of states in a 1D nano structure. (10)PART B Answer any two full questions, each carries 15 marks. a) Explain the working principle of Atomic Force Microscope. (10)b) Explain modulation doping and band formation in modulation doped (5) heterojunction. Differentiate between multiple quantum well and superlattice. (5) b) Explain Kronig Penney model of superlattice and the concept of zone folding. (10)a) Explain the working principle of Transmission Electron Microscopy. (10)b) Compare electron and optical microscopes. (5) **PART C** Answer any two full questions, each carries 20 marks. a) Explain resonant tunnel effect and the operation of resonant tunnel diode. (10)7 b) With the aid of energy band diagram, explain why MODFETs are high electron (6) mobility transistors Explain the principle of NEMS. (4) 8 a) Explain parallel transport in quantum structures and various scattering (10)mechanisms associated with this transport.

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	b)	Explain the formation of Landau levels and degeneracy associated with these levels.		(4)
9	c) a)) Explain Integer Quantum Hall effect.		(6) (10)
	b)	to observe Coulomb blockade effect. Explain the principle of quantum well subband photodetector.		(6)
	c)			(4)
